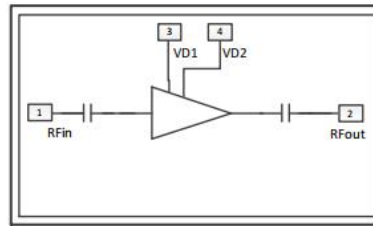


### Performance

- Frequency: 8.5~16GHz
- Typical Signal Gain: 16dB
- Typical Pout: 26dBm
- Mode: 0.25um HEMT
- Bias: 28V, Self Bias
- Size: 1.8\*1.2mm\*0.08mm

### Function Diagram

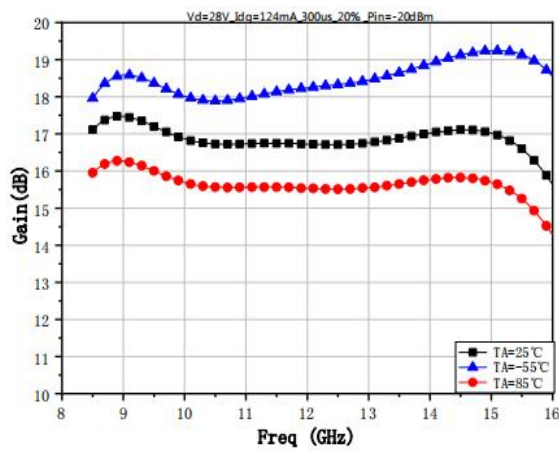


### Electrical Specifications (TA=25°C, Vd=28V, F: 8.5~16GHz, PL=300us, D.C=20%,)

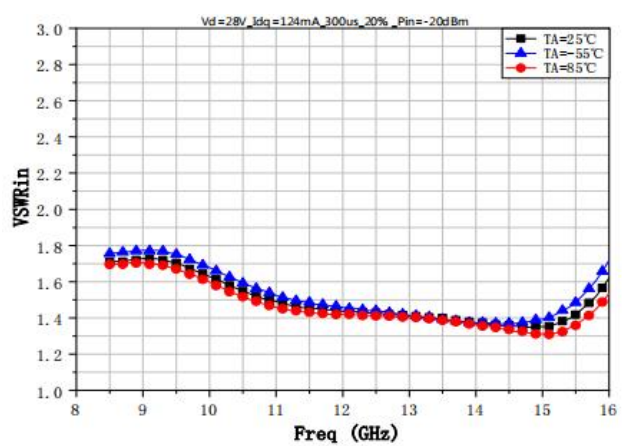
Symbol	Parameter	Min	Typical	Max	Unit
G	Small Signal Gain	-	16	-	dB
Gp	Power Gain	-	15	-	dB
Pout	Saturated Power	-	26	-	dBm
Id	Dynamic Current	-	0.12	-	A

### Test Curves

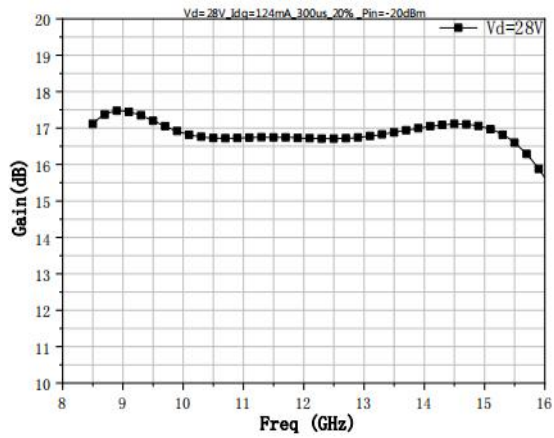
Small Signal Gain@ Different Temp



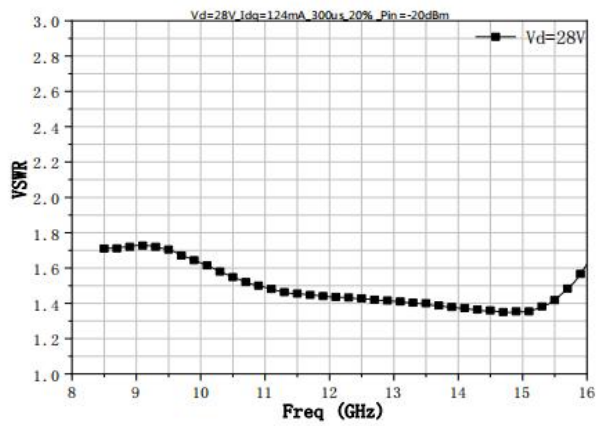
VSWRin@ Different Temp



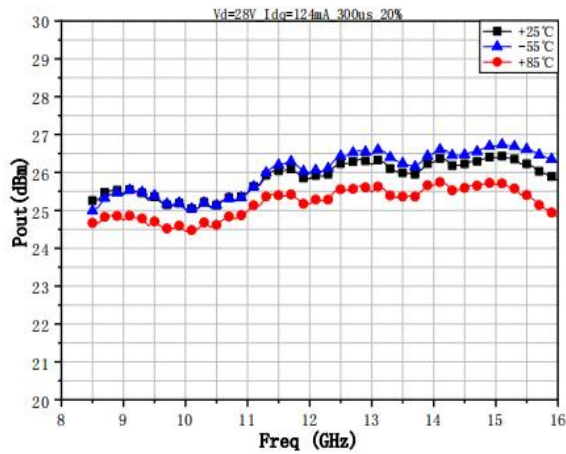
Gain@ Different Vd



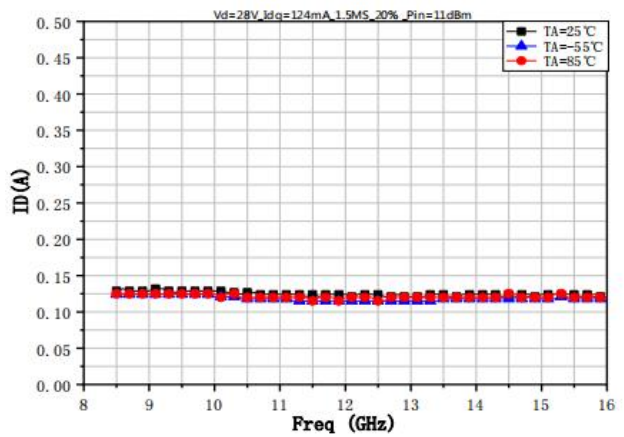
VSWRin@ Different Vd



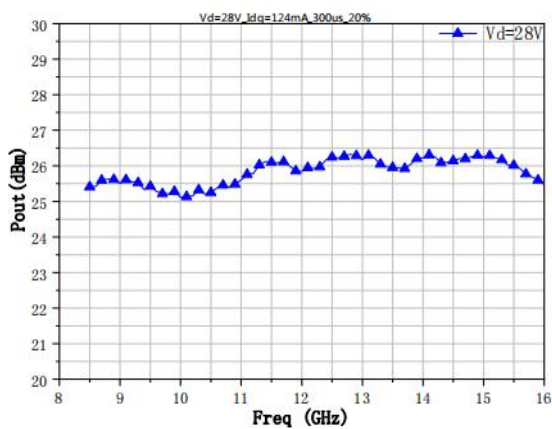
Pout@ Different Temp



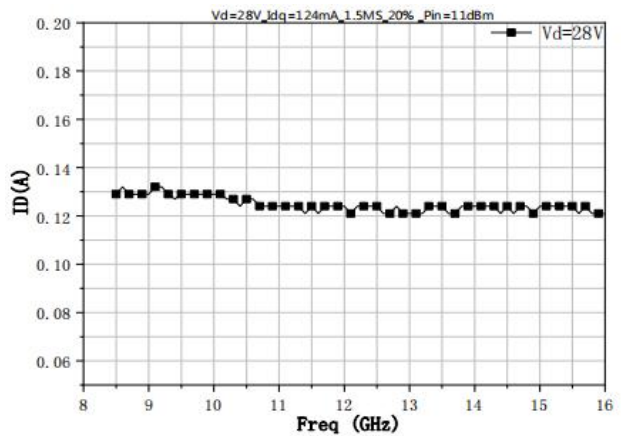
Id@ Different Temp



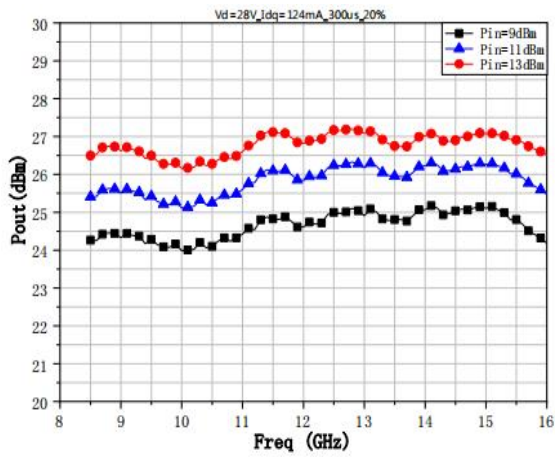
Pout@ Different Vd



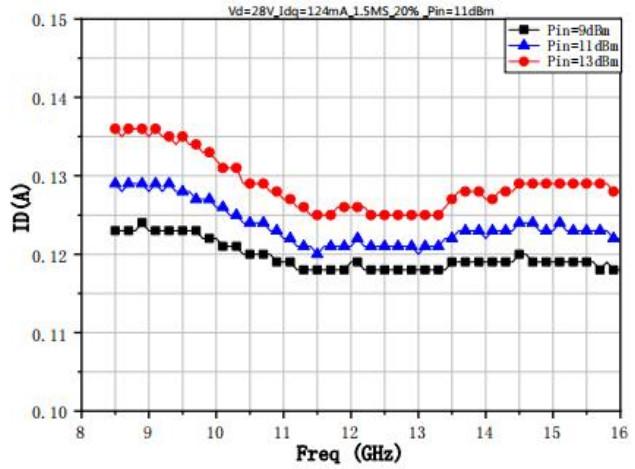
Id@ Different Vd



Pout@ Different Pin



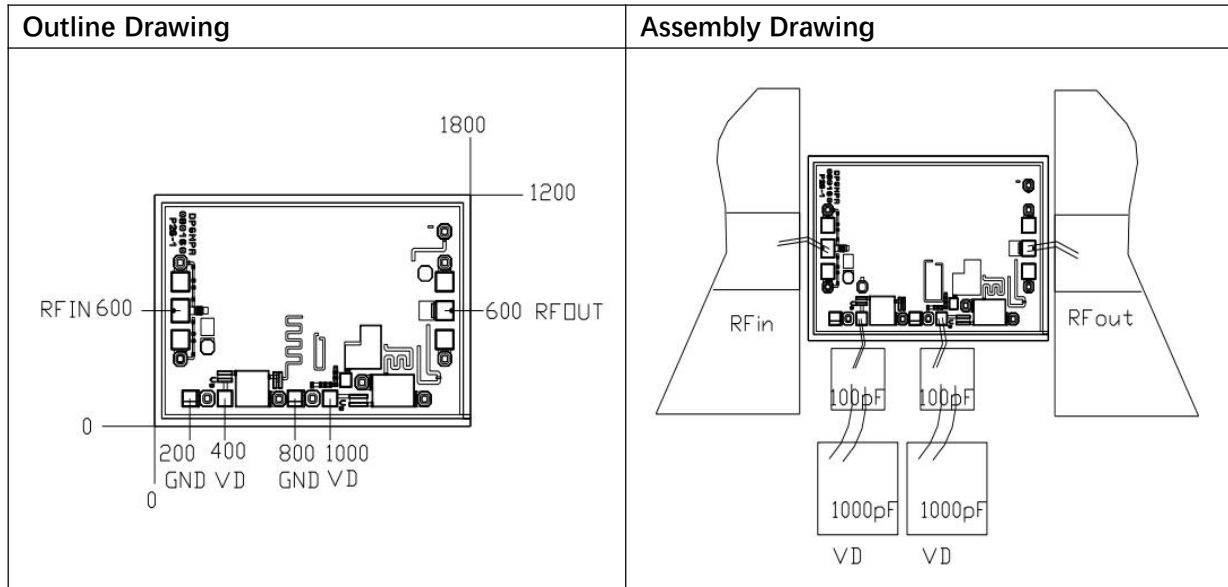
Id@ Different Pin



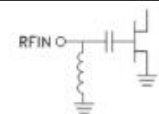


**Absolute Max Ratings (TA=25°C)**

Symbol	Parameter	Value	Remark
Vd	Drain Voltage	32V	
Id	Drain Current	1A	
Pd	DC Power	15W	
Pin	Input Power	20dBm	
Tch	Channel Temperature	225°C	
Tm	Mounting Temperature	310°C	1 min, N2 Protection
Tstg	Storage Temperature	-55~175°C	

Exceeding any one or combination of these limits may cause permanent damage.



### Pads Definition

Pad	Description	Equivalent Circuit
RFin	RF Signal input, connect to 50ohm system, no need block capacitor.	
RFout	RF Signal output, connect to 50ohm system, no need block capacitor.	
VD	Amp drain bias, external 100pF, 1000pF capacitor is needed	
GND	Bottom must connect to RF and DC ground	